BLF8G22LS-160BV

Power LDMOS transistor

AMPLEON

Rev. 3 — 1 September 2015

Product data sheet

1. Product profile

1.1 General description

160 W LDMOS power transistor with improved video bandwidth for base station applications at frequencies from 2000 MHz to 2200 MHz.

Table 1. Typical performance

Typical RF performance at $T_{case} = 25$ °C in a common source class-AB production test circuit.

| Test signal | f | I _{Dq} | V _{DS} | P _{L(AV)} | Gp | η_D | ACPR |
|------------------|--------------|-----------------|-----------------|--------------------|------|----------|--------------------|
| | (MHz) | (mA) | (V) | (W) | (dB) | (%) | (dBc) |
| 2-carrier W-CDMA | 2110 to 2170 | 1300 | 32 | 55 | 18.0 | 32 | -31 ^[1] |

^[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF; carrier spacing 5 MHz.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Decoupling leads to enable improved video bandwidth (100 MHz typical)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Integrated current sense
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

■ RF power amplifier for W-CDMA base stations and multi carrier applications in the 2000 MHz to 2200 MHz frequency range

2. Pinning information

Table 2. Pinning

| Pin | Description | Simplified outline | Graphic symbol |
|-----|------------------|--------------------|-----------------|
| 1 | drain | 4 | 4.4.57 |
| 2 | gate | $\frac{4}{0}$ | 1, 4, 5 7 |
| 3 | source [1] | | |
| 4,5 | video decoupling | 3 | 2-1 |
| 6 | sense gate | | 3 aaa-004156 |
| 7 | sense drain | 2 | |

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

| Type number | Packag | kage | | |
|-----------------|--------|---|----------|--|
| | Name | Description | Version | |
| BLF8G22LS-160BV | - | earless flanged LDMOST ceramic package; 6 leads | SOT1120B | |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------------|---------------------------|------------|------|------|------|
| V_{DS} | drain-source voltage | | - | 65 | V |
| V_{GS} | gate-source voltage | | -0.5 | +13 | V |
| V _{GS(sense)} | sense gate-source voltage | | -0.5 | +9 | V |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | - | 200 | °C |
| T _{case} | case temperature | [1] | - | 150 | °C |

^[1] Continuous use at maximum temperature will affect MTTF.

5. Recommended operating conditions

Table 5. Operating conditions

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-------------------|------------------|------------|-----|-----|------|------|
| T _{case} | case temperature | | -40 | - | +125 | °C |

6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Тур | Unit |
|----------------------|--|----------------------------------|------|------|
| R _{th(j-c)} | thermal resistance from junction to case | T_{case} = 80 °C; P_L = 55 W | 0.27 | K/W |

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7. Characteristics

Table 7. Characteristics

 $T_i = 25$ °C; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|----------------------------------|--|------|------|------|------|
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $V_{GS} = 0 \text{ V}; I_D = 2.16 \text{ mA}$ | 65 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | V _{DS} = 10 V; I _D = 216 mA | 1.5 | 1.9 | 2.3 | V |
| I _{DSS} | drain leakage current | V _{GS} = 0 V; V _{DS} = 28 V | - | - | 4.5 | μΑ |
| I _{DSX} | drain cut-off current | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$ | - | 40 | - | Α |
| I _{GSS} | gate leakage current | V _{GS} = 11 V; V _{DS} = 0 V | - | - | 450 | nA |
| g _{fs} | forward transconductance | V _{DS} = 10 V; I _D = 10.8 A | - | 16 | - | S |
| R _{DS(on)} | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 7.56 \text{ A}$ | - | 0.06 | - | Ω |
| I_{Dq} | quiescent drain current | main transitor: | 1175 | 1300 | 1425 | mA |
| | | V _{DS} = 32 V | | | | |
| | | sense transitor: | | | | |
| | | I _{DS} = 23.4 mA; V _{DS} = 30.4 V | | | | |

8. Test information

Table 8. Application information

Test signal: 2-carrier W-CDMA; PAR 8.4 dB at 0.01 % probability on CCDF; 3GPP test model 1; 64 DPCH; f_1 = 2112.5 MHz; f_2 = 2117.5 MHz; f_3 = 2162.5 MHz; f_4 = 2167.5 MHz; RF performance at V_{DS} = 32 V; I_{Dq} = 1300 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|--------------------------------------|---------------------------|------|------|------|------|
| Gp | power gain | P _{L(AV)} = 55 W | 16.8 | 18.0 | 19.7 | dB |
| RLin | input return loss | P _{L(AV)} = 55 W | - | -13 | -7 | dB |
| η_{D} | drain efficiency | P _{L(AV)} = 55 W | 29 | 32 | - | % |
| ACPR _{5M} | adjacent channel power ratio (5 MHz) | P _{L(AV)} = 55 W | - | -31 | -28 | dBc |

Table 9. Application information

Mode of operation: 1-carrier W-CDMA; PAR 7.2 dB at 0.01 % probability on CCDF; 3GPP test model 1; 64 DPCH; f=2167.5 MHz; RF performance at $V_{DS}=32$ V; $I_{Dq}=1300$ mA; $T_{case}=25$ °C; unless otherwise specified; in a class-AB production test circuit.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|------------------------------|--|-----|-----|-----|------|
| PAR _O | output peak-to-average ratio | P _{L(AV)} = 115 W; at 0.01 % probability on CCDF | 3.9 | 4.3 | - | dB |
| $P_{L(M)}$ | peak output power | | 290 | 310 | - | W |

8.1 Ruggedness in class-AB operation

The BLF8G22LS-160BV is capable to withstand a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 32 V; I_{Dq} = 1300 mA; P_{L} = 160 W; f = 2110 MHz.

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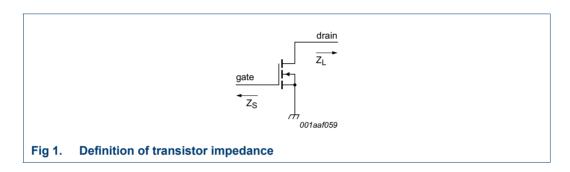
8.2 Impedance information

Table 10. Typical impedance

 $I_{Dq} = 1300 \text{ mA}$; main transistor $V_{DS} = 32 \text{ V}$.

| f | Z _S [1] | Z _L [1] |
|-------|--------------------|--------------------|
| (MHz) | (Ω) | (Ω) |
| 2110 | 2.2 – j4.6 | 1.4 – j2.8 |
| 2140 | 2.1 – j4.5 | 1.4 – j2.6 |
| 2170 | 2.1 – j4.3 | 1.3 – j2.4 |

[1] Z_S and Z_L defined in Figure 1.

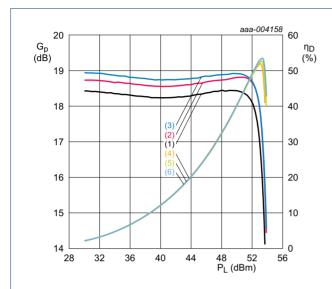


8.3 VBW in class-AB operation

The BLF8G22LS-160BV shows 100 MHz (typical) video bandwidth in class-AB test circuit in 2.1 GHz band at 32 V and 1.3 A.

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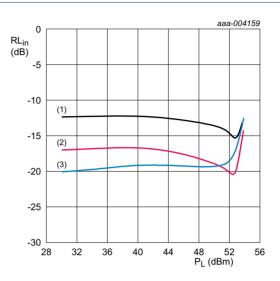
8.4 CW pulse



 V_{DS} = 32 V; I_{Dq} = 1300 mA.

- (1) G_p at f = 2110 MHz
- (2) G_p at f = 2140 MHz
- (3) G_p at f = 2170 MHz
- (4) η_D at f = 2110 MHz
- (5) η_D at f = 2140 MHz
- (6) η_D at f = 2170 MHz

Fig 2. Power gain and drain efficiency as function of load power; typical values



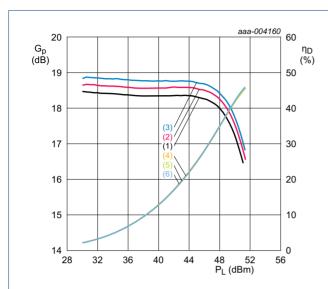
 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2110 MHz
- (2) f = 2140 MHz
- (3) f = 2170 MHz

Fig 3. Input return loss as a function of load power; typical values

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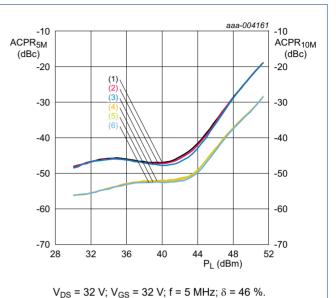
8.5 2-carrier W-CDMA



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

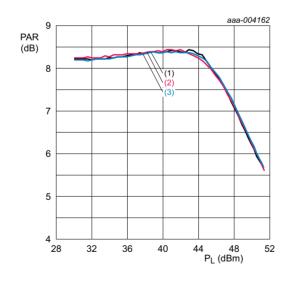
- (1) G_p at f = 2115 MHz
- (2) G_p at f = 2140 MHz
- (3) G_p at f = 2165 MHz
- (4) η_D at f = 2115 MHz
- (5) η_D at f = 2140 MHz
- (6) η_D at f = 2165 MHz

Fig 4. Power gain and drain efficiency as function of load power; typical values



- (1) ACPR_{5M} at f = 2115 MHz
- (2) ACPR_{5M} at f = 2140 MHz
- (3) ACPR_{5M} at f = 2165 MHz
- (4) ACPR_{10M} at f = 2115 MHz
- (5) ACPR_{10M} at f = 2140 MHz
- (6) ACPR_{10M} at f = 2165 MHz

Fig 5. Adjacent channel power ratio (5MHz) and adjacent channel power ratio (10MHz) as function of load power; typical values



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

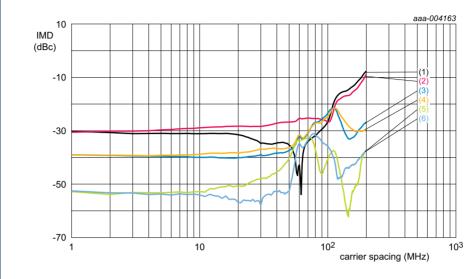
- (1) f = 2115 MHz
- (2) f = 2140 MHz
- (3) f = 2165 MHz

Fig 6. Peak to average power ratio as a function of load power; typical values

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8.6 2-tone VBW



 V_{DS} = 32 V; I_{Dq} = 1300 mA; f_c = 2140 MHz.

- (1) IMD3 low
- (2) IMD3 high
- (3) IMD5 low
- (4) IMD5 high
- (5) IMD7 low
- (6) IMD7 high

Fig 7. VBW capability in class-AB test circuit

8.7 Test circuit

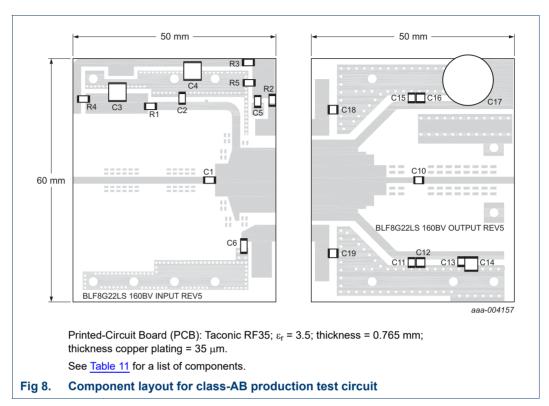


Table 11. List of components

For test circuit see [8].

| Component | Description | Value | Remarks |
|-------------------------------|-----------------------------------|------------------|--------------|
| C1, C2, C10, C11, C13, C15 | multilayer ceramic chip capacitor | 12 pF [1] | ATC100B |
| C5, C6 | multilayer ceramic chip capacitor | 120 pF [1] | ATC100B |
| C3, C4, C12, C16, C18, C19 | multilayer ceramic chip capacitor | 4.7 μF, 50 V [2] | Murata |
| C14 | multilayer ceramic chip capacitor | 4.7 μF, 100 V | TDK |
| C15 | electrolytic capacitor | 470 μF, 63 V | |
| R1 | SMD resistor | 4.7 Ω | Philips 1206 |
| R2 | SMD resistor | 470 Ω | Philips 1206 |
| R3 | SMD resistor | 820 Ω | Philips 1206 |
| R4 | SMD resistor | 12 Ω | Philips 1206 |
| R5 | SMD resistor | 2200 Ω | Philips 1206 |

- [1] American Technical Ceramics type 100B or capacitor of same quality.
- [2] Murata or capacitor of same quality.
- [3] TDK or capacitor of same quality.

9. Package outline

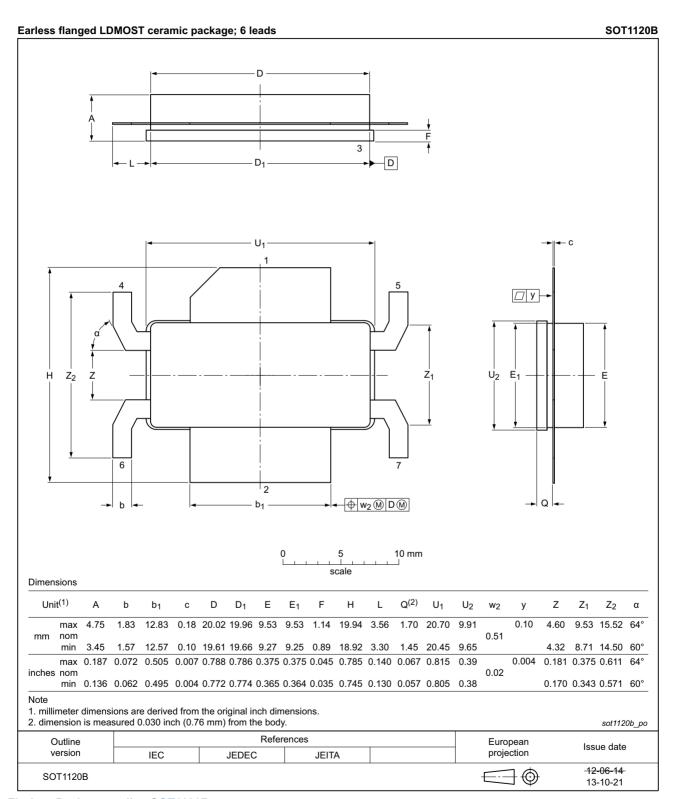


Fig 9. Package outline SOT1120B

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10. Abbreviations

Table 12. Abbreviations

| Acronym | Description |
|---------|---|
| 3GPP | Third Generation Partnership Project |
| CCDF | Complementary Cumulative Distribution Function |
| DPCH | Dedicated Physical CHannel |
| ESD | ElectroStatic Discharge |
| LDMOS | Laterally Diffused Metal Oxide Semiconductor |
| LDMOST | Laterally Diffused Metal Oxide Semiconductor Transistor |
| MTTF | Mean Time To Failure |
| PAR | Peak-to-Average Ratio |
| SMD | Surface Mounted Device |
| VBW | Video BandWidth |
| VSWR | Voltage Standing Wave Ratio |
| W-CDMA | Wideband Code Division Multiple Access |

11. Revision history

Table 13. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | |
|---------------------|--|--------------------|---------------|---------------------|--|
| BLF8G22LS-160BV#3 | 20150901 | Product data sheet | | BLF8G22LS-160BV v.2 | |
| Modifications: | The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. | | | | |
| | Legal texts have been adapted to the new company name where appropriate. | | | | |
| BLF8G22LS-160BV v.2 | 20150501 | Product data sheet | - | BLF8G22LS-160BV v.1 | |
| BLF8G22LS-160BV v.1 | 20120625 | Product data sheet | - | - | |

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| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
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